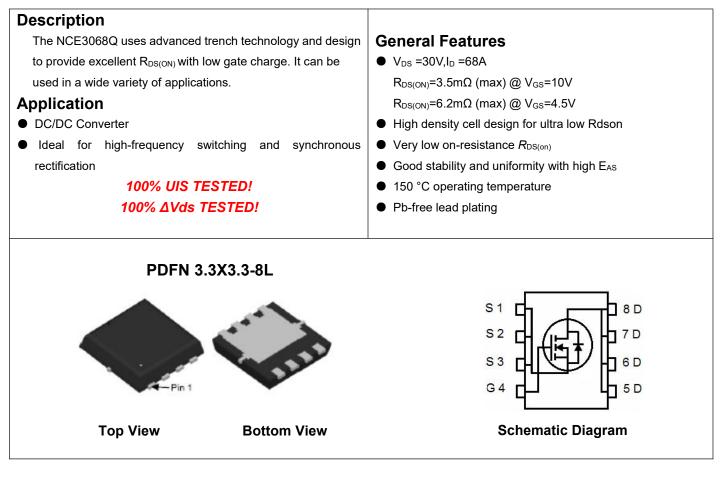


NCE N-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3068Q	NCE3068Q	PDFN 3.3X3.3-8L	-	-	-

Absolute Maximum Ratings (Tc=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	30	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	Ι _D	68	А	
Drain Current-Continuous(Tc=100℃)	I _D (100℃)	48	A	
Pulsed Drain Current (Note 1)	I _{DM}	272	A	
Maximum Power Dissipation	PD	45	W	
Derating factor		0.36	W/°C	
Single pulse avalanche energy (Note 5)	E _{AS}	150	mJ	
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	Rejc	2.78	°C/W
Thermal Resistance, Junction-to-Ambient ^(Note 2)	R _{0JA}	60	°C/W



Electrical Characteristics (TC=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30	-	-	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =30V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	1					
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1	1.5	2.2	V
Drain Source On State Resistance		V _{GS} =10V, I _D =20A	-	3.5	4.1	- mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =20A	-	6.2	7.5	
Gate resistance	R _G	V _{DS} =0V,V _{GS} =0V,F=1.0MHz	-	1.9	-	Ω
Forward Transconductance	g fs	V _{DS} =10V,I _D =20A	-	30	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}		-	1784	-	pF
Output Capacitance	Coss	V _{DS} =15V,V _{GS} =0V,	-	266	-	pF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	212	-	pF
Switching Characteristics (Note 4)	I					
Turn-on Delay Time	t _{d(on)}		-	7	-	nS
Turn-on Rise Time	tr	V _{DD} =5V,I _D =20A	-	6	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =6 Ω	-	30	-	nS
Turn-Off Fall Time	t _f		-	8	-	nS
Total Gate Charge	Qg	N/ 451/1 000	-	38.4	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =15V,I _D =20A,	-	5.8	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	7.9	-	nC
Drain-Source Diode Characteristics	1					
Diode Forward Voltage (Note 3)	Vsd	V _{GS} =0V,I _S =20A	-	0.85	1.2	V
Diode Forward Current (Note 2)	ls		-	-	68	А
Reverse Recovery Time	trr	TJ = 25°C, I _F = 20A	-	47	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	47	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is neglig	ible (turi	n-on is do	minated b	y LS+LD)

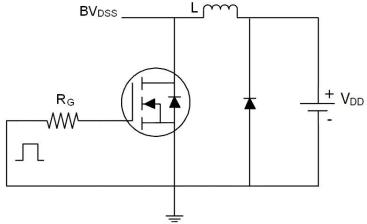
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz.Copper, in a still air environment with $T_A = 25^{\circ}$ C. The maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^\circ\!\mathrm{C}$,V_{DD}=15V,V_G=10V,L=0.5mH,Rg=25\Omega

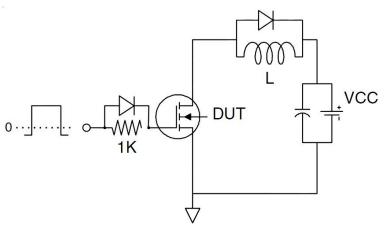


Test Circuit

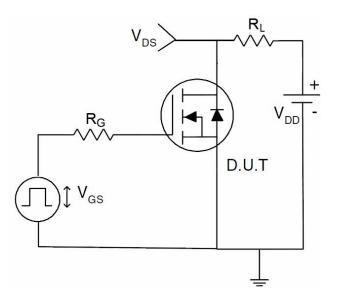
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit

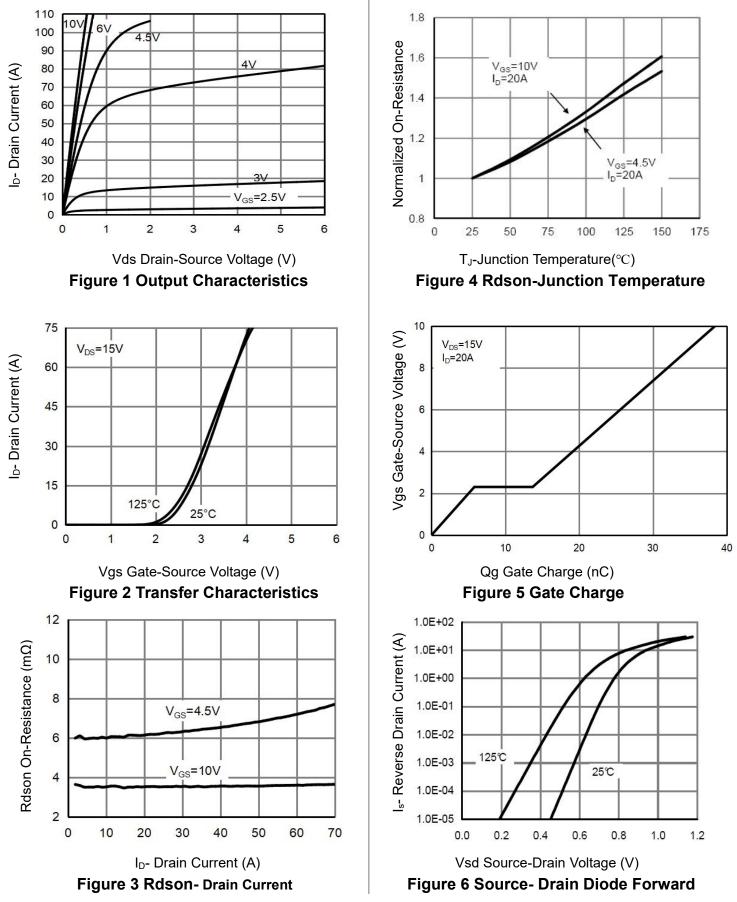


3) Switch Time Test Circuit





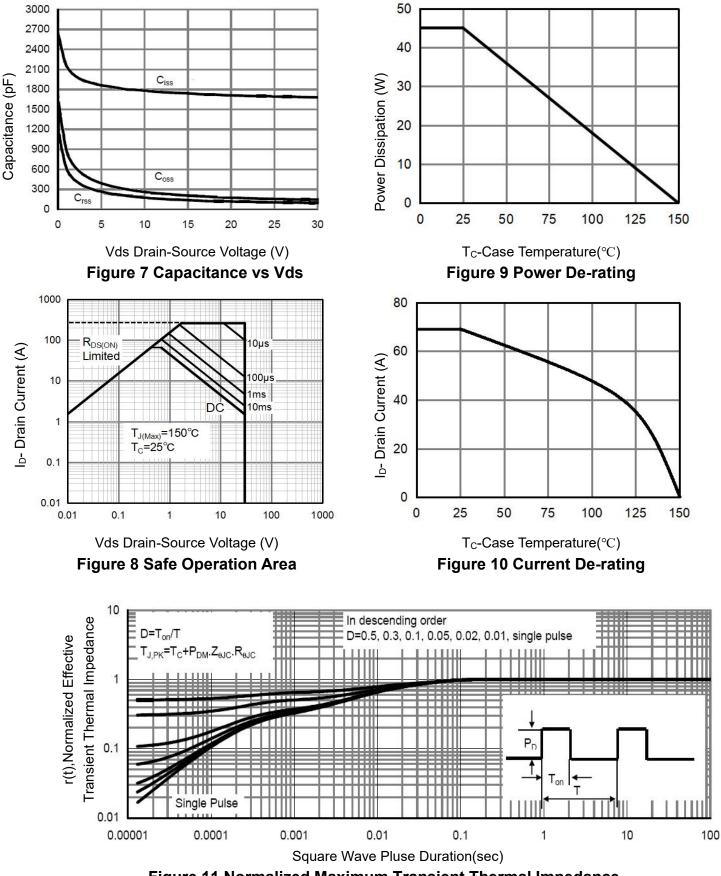
Typical Electrical and Thermal Characteristics (Curves)





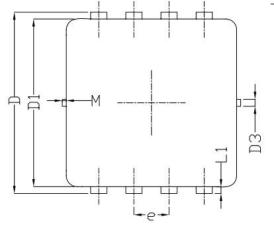
http://www.ncepower.com

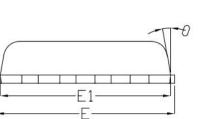
NCE3068Q

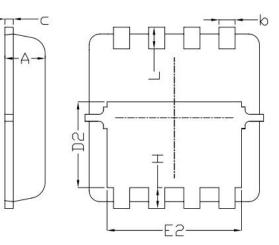


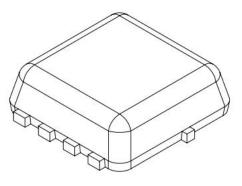


PDFN3.3X3.3-8L Package Information



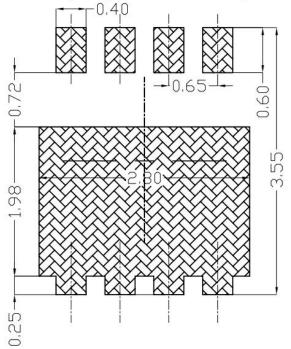






SYMBOL	DIMENSIONAL REQMTS				
	MIN	NOM	MAX		
A	0.70	0.75	0.80		
b	0.25	0.30	0.35		
с	0.10	0.15	0.25		
D	3.25	3.35	3.45		
D1	3.00	3.10	3.20		
D2	1.48	1.58	1.68		
D3		0.13			
Ε	3.20	3.30	3.40		
E1	3.00	3.15	3.20		
E2	2.39	2.49	2.59		
е		0.65BSC			
H	0.30	0.39	0.50		
L	0.30	0.40	0.50		
L1		0.13			
θ		10°	12°		
M	*	*	0.15		

Land Pattern (Only for Reference)





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